

# 40V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
-40V	$13m\Omega @ V_{GS} = -10V$	-10.3A
	$18m\Omega @ V_{GS} = -4.5V$	-8.8A

### **Features and Benefits**

- Low R<sub>DS(ON)</sub> ensures on state losses are minimized.
- Small form factor thermally efficient package enables higher density end products.
- Occupies 33% of the board area occupied by SO-8, enabling smaller end product.
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

# **Description and Applications**

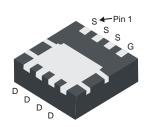
This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

### **Mechanical Data**

- Case: POWERDI®3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 © 3
- Weight: 0.072 grams (Approximate)

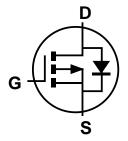
#### POWERDI®3333-8







Top View



### **Equivalent Circuit**

### **Ordering Information** (Note 4)

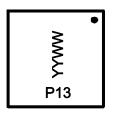
Part Number	Case	Packaging
DMP4013LFG-7	POWERDI®3333-8	2,000/Tape & Reel
DMP4013LFG-13	POWERDI®3333-8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**

#### POWERDI®3333-8



P13= Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 13 = 2013) WW = Week Code (01 ~ 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	$V_{DSS}$	-40	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	I <sub>D</sub>	-10.3 -8.3	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	t<10s	$T_A = +25$ °C $T_A = +70$ °C	I <sub>D</sub>	-13.7 -11	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	80	Α		
Maximum Continuous Body Diode Forward Current (	Is	2.6	Α		
Avalanche Current, L = 0.1mH	I <sub>AS</sub>	34	Α		
Avalanche Energy, L = 0.1mH	Eas	58	mJ		

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)		P <sub>D</sub>	1	W
Thermal Resistance, Junction to Ambient (Note 5)  Steady St. t<10s		$R_{ heta JA}$	123	°C/W
			69	
Total Power Dissipation (Note 6)		P <sub>D</sub>	2.1	W
Thermal Besistance Hungtion to Ambient (Note 6)		Б	60	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ hetaJA}$	34	°C/W
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	3.3		
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = ±25°C, unless otherwise specified.)

Characteristic		Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage		-40		_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	_	_	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage		_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1	_	-3	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$	
Static Drain-Source On-Resistance	В	_	9.4	13		$V_{GS} = -10V, I_D = -10A$	
Static Dialii-Source Off-Resistance	R <sub>DS (ON)</sub>	_	12.3	18	mΩ	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -8A	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	3,426	_	pF	.,	
Output Capacitance	Coss	_	283	_	pF	$V_{DS} = -20V, V_{GS} = 0V,$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	235	_	pF	T = TIVITIZ	
Gate Resistance	Rg	_	4.7	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	32.5	_	nC		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	68.6	_	nC	1, 20, 1, 40,	
Gate-Source Charge	Q <sub>gs</sub>	_	8.2	_	nC	V <sub>DS</sub> = -20V, I <sub>D</sub> = -10A	
Gate-Drain Charge	$Q_{gd}$	_	9.9	_	nC		
Turn-On Delay Time	t <sub>D(on)</sub>	_	5.3	_	ns		
Turn-On Rise Time	t <sub>r</sub>	_	20	_	ns	$V_{DD} = -20V, V_{GEN} = -10V,$ $R_G = 3\Omega, I_D = -10A$	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	126	-	ns		
Turn-Off Fall Time	t <sub>f</sub>	_	83	_	ns		
Body Diode Reverse Recovery Time	t <sub>rr</sub>	_	19.5	_	nS	100 11/11 1000/	
Body Diode Reverse Recovery Charge	Qrr	_	9.8	_	nC	I <sub>F</sub> = -10A, di/dt = 100A/μs	

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Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

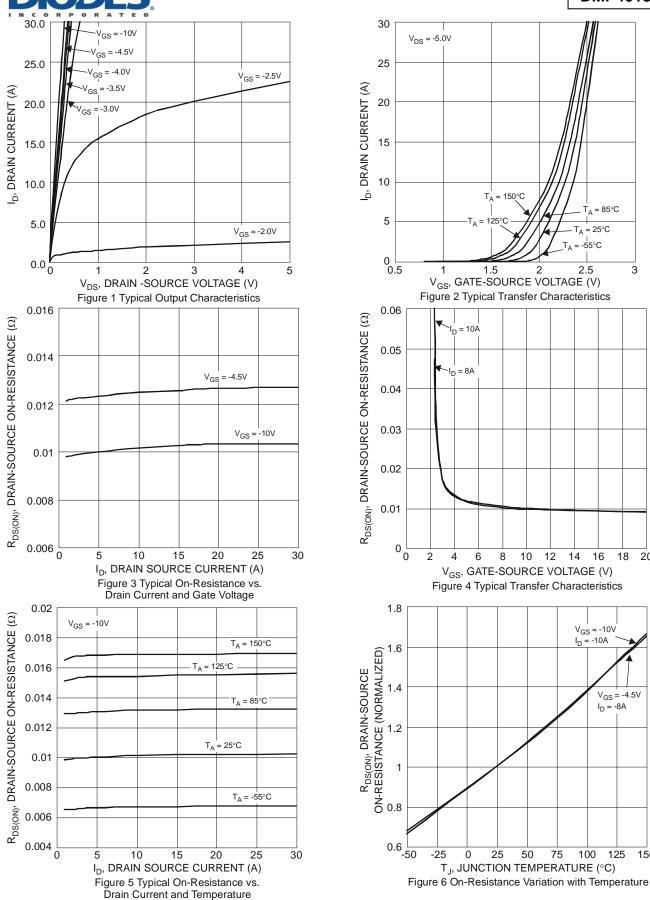
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

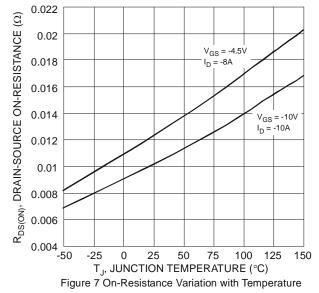
## DMP4013LFG

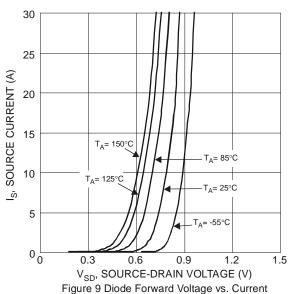
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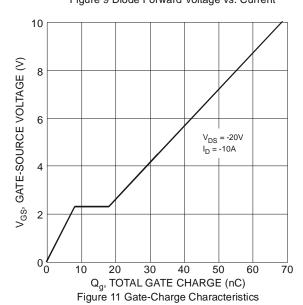
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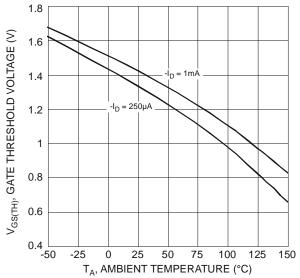
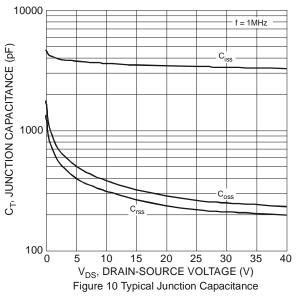
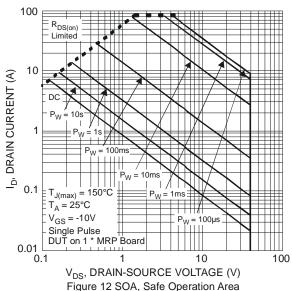
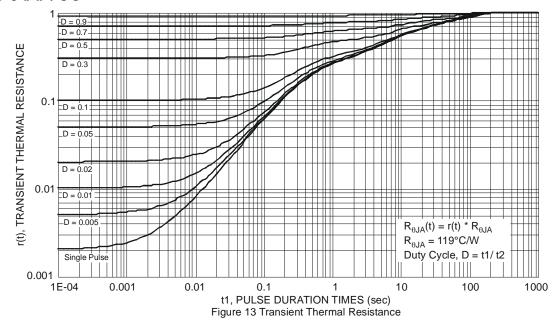


Figure 8 Gate Threshold Variation vs. Ambient Temperature







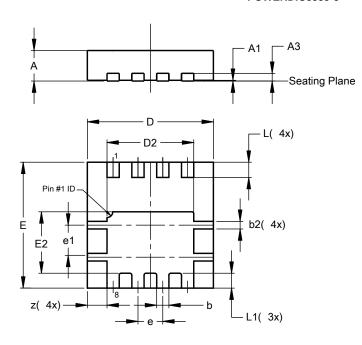




# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### POWERDI®3333-8



POWERDI®3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	_	_	0.203			
b	0.27	0.37	0.32			
b2	_	_	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
E	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
е	-	_	0.65			
e1	0.79	0.89	0.84			
L	0.35	0.45	0.40			
L1	_	_	0.39			
Z	_	_	0.515			
All Dimensions in mm						

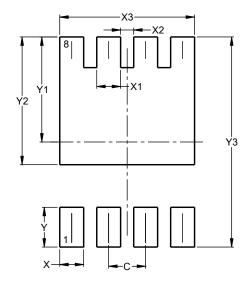
# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

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Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Υ	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		



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